100 mA Adjustable Output, **Positive Voltage Regulator**

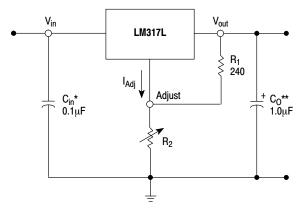
The LM317L is an adjustable 3-terminal positive voltage regulator capable of supplying in excess of 100 mA over an output voltage range of 1.2 V to 37 V. This voltage regulator is exceptionally easy to use and requires only two external resistors to set the output voltage. Further, it employs internal current limiting, thermal shutdown and safe area compensation, making them essentially blow-out proof.

The LM317L serves a wide variety of applications including local, on card regulation. This device can also be used to make a programmable output regulator, or by connecting a fixed resistor between the adjustment and output, the LM317L can be used as a precision current regulator.

Features

- Output Current in Excess of 100 mA
- Output Adjustable Between 1.2 V and 37 V
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe-Area Compensation
- Floating Operation for High Voltage Applications
- Standard 3-Lead Transistor Package
- Eliminates Stocking Many Fixed Voltages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

Simplified Application



- * C_{in} is required if regulator is located an appreciable distance from power supply filter.
- ** Co is not needed for stability, however, it does improve transient response.

$$V_{out} \, = \, 1.25 \, \, V \left(1 \, + \frac{R_2}{R_1} \right) \, + \, I_{Adj} \, R_2$$

Since $I_{\mbox{\scriptsize Adi}}$ is controlled to less than 100 $\mbox{$\mu$A},$ the error associated with this term is negligible in most applications.



ON Semiconductor®

www.onsemi.com

LOW CURRENT THREE-TERMINAL ADJUSTABLE POSITIVE **VOLTAGE REGULATOR**



SOIC-8 **D SUFFIX CASE 751** 1. V_{in}

2. V_{out}

 V_{out}
 Adjust 5. N.C.

6. V_{out}

7. V_{out} 8. N.C



STRAIGHT LEAD **BULK PACK**

BENT LEAD TAPE & REEL

AMMO PACK Pin 1. Adjust 2. V_{out}

TO-92 **Z SUFFIX CASE 29**

3. V_{in}

ORDERING INFORMATION See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input-Output Voltage Differential	V _I –V _O	40	Vdc
Power Dissipation Case 29 (TO–92) T _A = 25°C Thermal Resistance, Junction–to–Ambient Thermal Resistance, Junction–to–Case	P _D R _{θJA} R _θ JC	Internally Limited 160 83	W °C/W °C/W
Case 751 (SOIC-8) (Note 1) T _A = 25°C Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case	P _D R _{θJA} R _{θJC}	Internally Limited 180 45	W °C/W °C/W
Maximum Junction Temperature	T _{JMAX}	+150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. SOIC-8 Junction-to-Ambient Thermal Resistance is for minimum recommended pad size. Refer to Figure 24 for Thermal Resistance variation versus pad size.
- This device series contains ESD protection and exceeds the following tests: Human Body Model, 2000 V per MIL STD 883, Method 3015.
 Machine Model Method, 200 V.

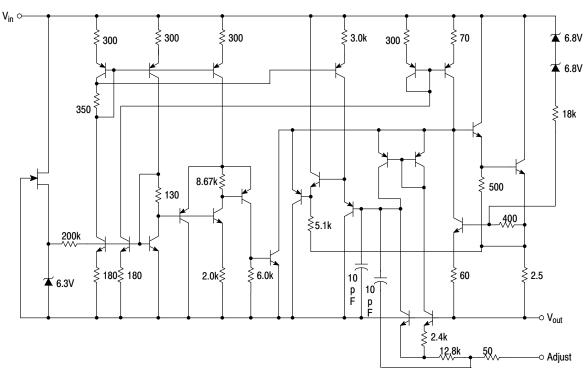


Figure 1. Representative Schematic Diagram

ELECTRICAL CHARACTERISTICS

 $(V_I - V_O = 5.0 \text{ V}; I_O = 40 \text{ mA}; T_J = T_{low} \text{ to } T_{high} \text{ (Note 3)}; I_{max} \text{ and } P_{max} \text{ (Note 4)}; unless otherwise noted.)}$

			LM317L, LB, NCV317LB			
Characteristics	Figure	Symbol	Min	Тур	Max	Unit
Line Regulation (Note 5) $T_A = 25^{\circ}C, 3.0 \text{ V} \le V_I - V_O \le 40 \text{ V}$	1	Reg _{line}	-	0.01	0.04	%/V
Load Regulation (Note 5), $T_A = 25^{\circ}C$ 10 mA $\leq I_O \leq I_{max} - LM317L$ $V_O \leq 5.0 \text{ V}$ $V_O \geq 5.0 \text{ V}$	2	Reg _{load}	- -	5.0 0.1	25 0.5	mV % V _O
Adjustment Pin Current	3	I _{Adj}	-	50	100	μА
Adjustment Pin Current Change $2.5 \text{ V} \le \text{V}_I - \text{V}_O \le 40 \text{ V}, \text{ P}_D \le \text{P}_{\text{max}}$ $10 \text{ mA} \le \text{I}_O \le \text{I}_{\text{max}} - \text{LM317L}$	1, 2	ΔI_{Adj}	-	0.2	5.0	μΑ
Reference Voltage 3.0 V \leq V _I $-$ V _O \leq 40 V, P _D \leq P _{max} 10 mA \leq I _O \leq I _{max} $-$ LM317L	3	V _{ref}	1.20	1.25	1.30	V
Line Regulation (Note 5), $3.0 \text{ V} \le \text{V}_1 - \text{V}_0 \le 40 \text{ V}$	1	Reg _{line}	_	0.02	0.07	%/V
Load Regulation (Note 5) 10 mA \leq I _O \leq I _{max} – LM317L V _O \leq 5.0 V V _O \geq 5.0 V	2	Reg _{load}	- -	20 0.3	70 1.5	mV % V _O
Temperature Stability $(T_{low} \le T_J \le T_{high})$	3	T _S	_	0.7	-	% V _O
Minimum Load Current to Maintain Regulation $(V_I - V_O = 40 \text{ V})$	3	I _{Lmin}	_	3.5	10	mA
$\begin{aligned} &\text{Maximum Output Current} \\ &\text{$V_I-V_O \le 6.25 \ V$, $P_D \le P_{max}$, Z Package} \\ &\text{$V_I-V_O \le 40 \ V$, $P_D \le P_{max}$, $T_A = 25^{\circ}C$, Z Package} \end{aligned}$	3	I _{max}	100 –	200 20	- -	mA
RMS Noise, % of V_O $T_A = 25^{\circ}C$, 10 Hz \leq f \leq 10 kHz	-	N	-	0.003	-	% Vo
Ripple Rejection (Note 6) $V_O = 1.2 \text{ V}, f = 120 \text{ Hz}$ $C_{Adj} = 10 \mu\text{F}, V_O = 10.0 \text{ V}$	4	RR	60 -	80 80	- -	dB
Thermal Shutdown (Note 7)	-	_	-	180	_	°C
Long Term Stability, $T_J = T_{high}$ (Note 8) $T_A = 25^{\circ}C$ for Endpoint Measurements	3	S	-	0.3	1.0	%/1.0 k Hrs.

^{8.} Since Long-Term Stability cannot be measured on each device before shipment, this specification is an engineering estimate of average stability from lot to lot.

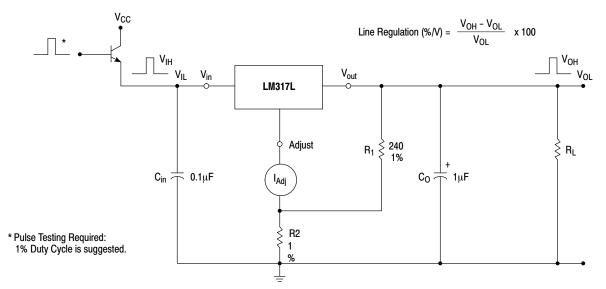


Figure 2. Line Regulation and $\Delta I_{\mbox{\sc Adj}}\mbox{/Line Test Circuit}$

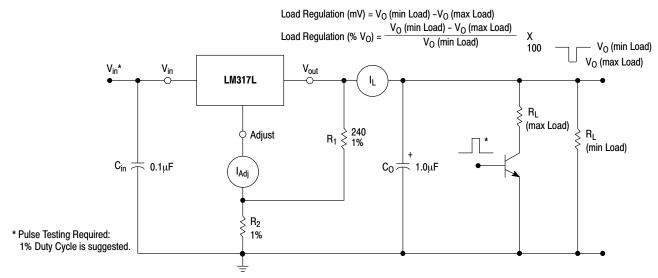


Figure 3. Load Regulation and $\Delta I_{Adj}/Load$ Test Circuit

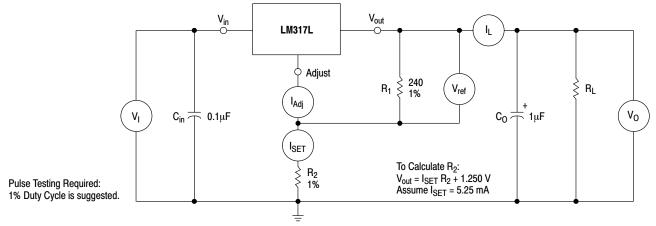


Figure 4. Standard Test Circuit

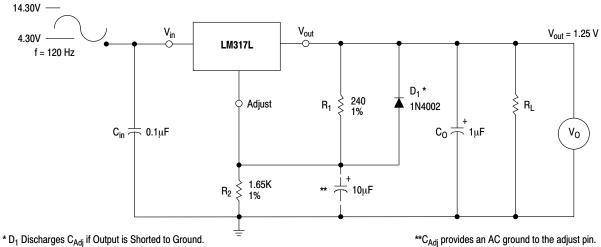


Figure 5. Ripple Rejection Test Circuit

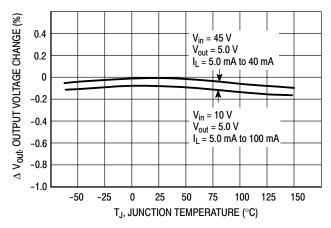


Figure 6. Load Regulation

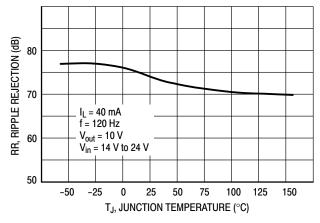


Figure 7. Ripple Rejection

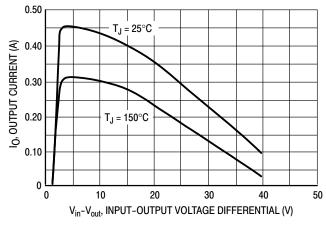


Figure 8. Current Limit

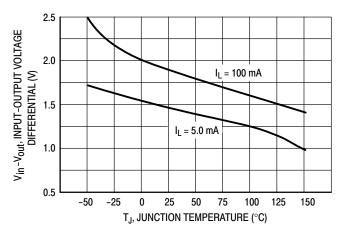


Figure 9. Dropout Voltage

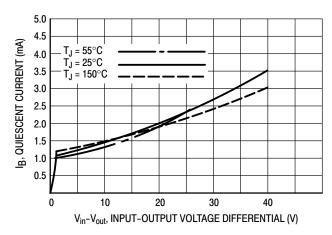


Figure 10. Minimum Operating Current

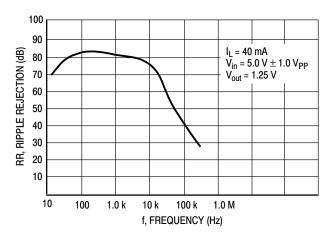


Figure 11. Ripple Rejection versus Frequency

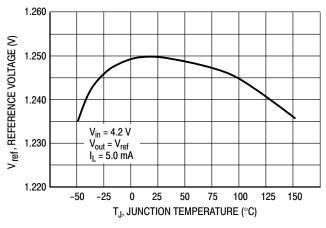


Figure 12. Temperature Stability

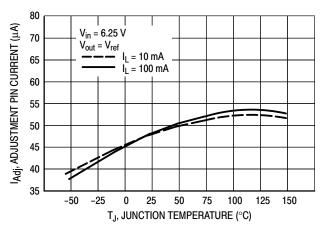


Figure 13. Adjustment Pin Current

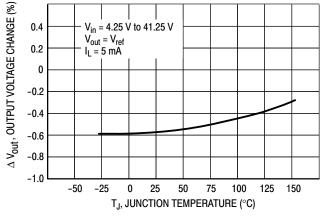


Figure 14. Line Regulation

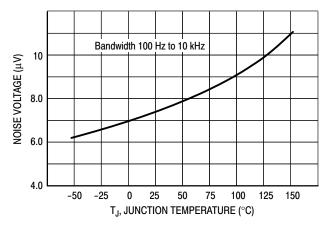


Figure 15. Output Noise

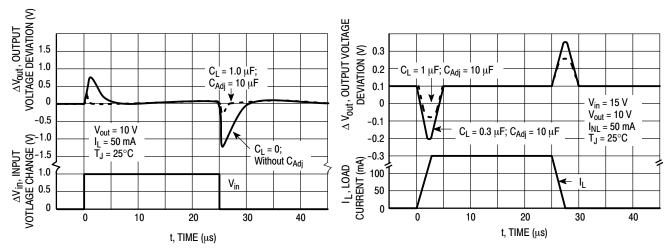


Figure 16. Line Transient Response

Figure 17. Load Transient Response

APPLICATIONS INFORMATION

Basic Circuit Operation

The LM317L is a 3–terminal floating regulator. In operation, the LM317L develops and maintains a nominal 1.25 V reference (V_{ref}) between its output and adjustment terminals. This reference voltage is converted to a programming current (I_{PROG}) by R_1 (see Figure 13), and this constant current flows through R_2 to ground. The regulated output voltage is given by:

$$V_{out} = V_{ref} (1 + \frac{R_2}{R_1}) + I_{Adj} R_2$$

Since the current from the adjustment terminal (I_{Adj}) represents an error term in the equation, the LM317L was designed to control I_{Adj} to less than 100 μA and keep it constant. To do this, all quiescent operating current is returned to the output terminal. This imposes the requirement for a minimum load current. If the load current is less than this minimum, the output voltage will rise.

Since the LM317L is a floating regulator, it is only the voltage differential across the circuit which is important to performance, and operation at high voltages with respect to ground is possible.

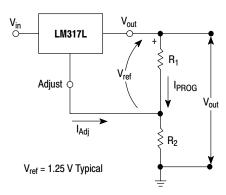


Figure 18. Basic Circuit Configuration

Load Regulation

The LM317L is capable of providing extremely good load regulation, but a few precautions are needed to obtain maximum performance. For best performance, the programming resistor (R1) should be connected as close to the regulator as possible to minimize line drops which effectively appear in series with the reference, thereby degrading regulation. The ground end of R2 can be returned near the load ground to provide remote ground sensing and improve load regulation.

External Capacitors

A 0.1 μF disc or 1.0 μF tantalum input bypass capacitor (C_{in}) is recommended to reduce the sensitivity to input line impedance.

The adjustment terminal may be bypassed to ground to improve ripple rejection. This capacitor (C_{Adj}) prevents ripple from being amplified as the output voltage is increased. A 10 μF capacitor should improve ripple rejection about 15 dB at 120 Hz in a 10 V application.

Although the LM317L is stable with no output capacitance, like any feedback circuit, certain values of external capacitance can cause excessive ringing. An output capacitance (C_O) in the form of a 1.0 μ F tantalum or 25 μ F aluminum electrolytic capacitor on the output swamps this effect and insures stability.

Protection Diodes

When external capacitors are used with any IC regulator it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator.

Figure 14 shows the LM317L with the recommended protection diodes for output voltages in excess of 25 V or high capacitance values ($C_O > 10~\mu F, \, C_{Adj} > 5.0~\mu F$). Diode D_1 prevents C_O from discharging thru the IC during an input short circuit. Diode D_2 protects against capacitor C_{Adj} discharging through the IC during an output short circuit. The combination of diodes D_1 and D_2 prevents C_{Adj} from discharging through the IC during an input short circuit.

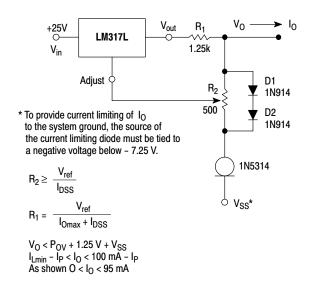


Figure 20. Adjustable Current Limiter

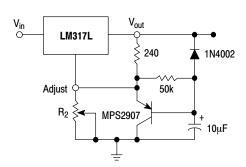


Figure 22. Slow Turn-On Regulator

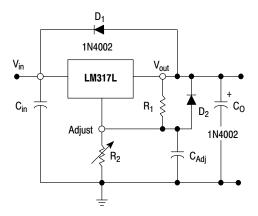
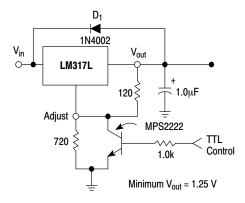


Figure 19. Voltage Regulator with Protection Diodes



D₁ protects the device during an input short circuit.

Figure 21. 5.0 V Electronic Shutdown Regulator

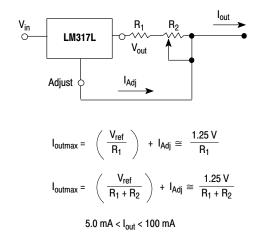


Figure 23. Current Regulator

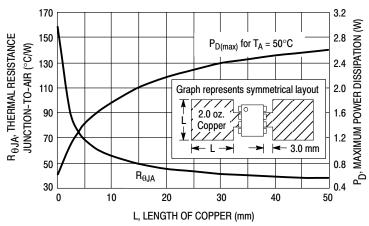


Figure 24. SOP-8 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

ORDERING INFORMATION

Device	Operating Temperature Range	Package	Shipping [†]
LM317LBDG		SOIC-8 (Pb-Free)	98 Units / Rail
LM317LBDR2G	7	SOIC-8 (Pb-Free)	2500/Tape & Reel
LM317LBZG	7	TO-92 (Pb-Free)	2000 Units / Bag
LM317LBZRAG	7	TO-92 (Pb-Free)	2000 Tape & Reel
LM317LBZRPG	$T_{J} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Ammo Pack
NCV317LBDG*	7	SOIC-8 (Pb-Free)	98 Units / Rail
NCV317LBDR2G*	7	SOIC-8 (Pb-Free)	2500/Tape & Reel
NCV317LBZG*	7	TO-92 (Pb-Free)	2000 Units / Bag
NCV317LBZRAG*]	TO-92 (Pb-Free)	2000 Tape & Reel
LM317LDG		SOIC-8 (Pb-Free)	98 Units / Rail
LM317LDR2G		SOIC-8 (Pb-Free)	2500/Tape & Reel
LM317LZG	$T_J = 0$ °C to +125°C	TO-92 (Pb-Free)	2000 Units / Bag
LM317LZRAG		TO-92 (Pb-Free)	2000 Tape & Reel
LM317LZREG		TO-92 (Pb-Free)	2000 Tape & Reel
LM317LZRMG	7	TO-92 (Pb-Free)	2000 Ammo Pack
LM317LZRPG		TO-92 (Pb-Free)	2000 Ammo Pack

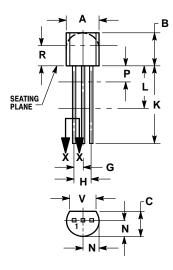
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NCV devices: T_{low} = -40°C, T_{high} = +125°C. Guaranteed by design. NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

TO-92 (TO-226) **Z SÙFFIX**

CASE 29-11 **ISSUE AM**



STRAIGHT LEAD **BULK PACK**



- NOTES:

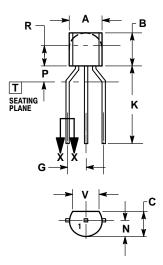
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. CONTOUR DO PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.

 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



BENT LEAD TAPE & REEL AMMO PACK



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS			
DIM	MIN	MAX		
Α	4.45	5.20		
В	4.32	5.33		
С	3.18	4.19		
D	0.40	0.54		
G	2.40	2.80		
J	0.39	0.50		
K	12.70			
N	2.04	2.66		
P	1.50	4.00		
R	2.93			
٧	3.43			

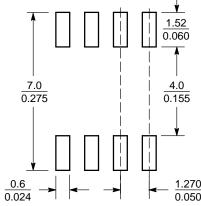
PACKAGE DIMENSIONS

SOIC-8 NB **D SUFFIX** CASE 751-07 **ISSUE AK** -X-В s 0.25 (0.010) M Y M -Y-G -C SEATING -Z-0.10 (0.004) 0.25 (0.010) M Z YS XS **SOLDERING FOOTPRINT***

NOTES:

- DIMENSIONING AND TOLERANCING PER
 ANSLY 14 FM 1082
- ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27 BSC		0.05	0 BSC	
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
М	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	



SCALE 6:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

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